# Effect of Uniaxial and Hydrostatic Strain on the Optical Constants and the Electronic Structure of Copper* 

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#### Abstract

The linear response of the optical constants of Cu to a general strain is presented for the range $1.5 \leq \pi \omega \leq 5.5 \mathrm{eV}$. The transitions $X_{5} \rightarrow X_{4}^{\prime}$ at 4.0 eV and $E_{F} \rightarrow L_{1}$ at 4.15 eV are identified. The deformation potentials $\partial\left(E_{F}-L_{3} \mathrm{upper}\right) / \partial e=-(1.1 \pm 0.1) \mathrm{eV}$ and $\partial\left(L_{1}-E_{F}\right) / \partial e=-(9.6 \pm 1.5) \mathrm{eV}$ with $e=\Delta V / V$, and $\partial L_{1} / \partial e_{y z}=-(72 \pm 12) \mathrm{eV}$ with $e_{x y}=e_{y z}=e_{x x}, e_{x x}=e_{y y}=e_{z z}=0$ for $\mathrm{k} \|[111]$ are evaluated from the measurements. They are used to derive the volume coefficients of the Fermi energy, $\partial\left(\ln E_{F}\right) / \partial e=-1.1 \pm 0.3$, and of the position of the $d$ bands, $\partial\left(\ln E_{d}\right) / \partial e=-1.2 \pm 0.5$, with respect to $\Gamma_{1}$. The measurements are consistent with the assumption that direct interband transitions dominate the absorption above 2 eV .


## INTRODUCTION

$A^{P}$PPLYING a shear strain to a single crystal reduces its symmetry and may split formerly de;enerate levels. In optical experiments, the first such splitting was observed accidentally in the investigation if the excitonic absorption of germanium. ${ }^{1-3}$ The power if the method was soon recognized; it was used to study the excitonic absorption of other crystals, e.g., $\mathrm{CdTe}^{4}$ and $\mathrm{Cu}_{2} \mathrm{O} .{ }^{5}$ The method was first applied to the continuous interband absorption by studying the straininduced change of the reflectance of Ge and $\mathrm{Si}^{6 .{ }^{6} 7}$ Yodulation techniques were also used successfully. ${ }^{8-10}$ Polycrystalline films of the noble metals were in"estigated. ${ }^{11} \mathrm{~A}$ preliminary version of the present paper ras published elsewhere. ${ }^{12}$
According to the band-structure calculations of $\mathrm{Cu},{ }^{13,14}$ direct, k -conserving interband transitions are possible for $h \omega>2 \mathrm{eV}$. These lead to a continuous :bsorption in contrast to the sharp excitonic structure

[^0]of solids mentioned above. However, the topology and the symmetry of the problem give rise to singularities in the joint density of states, ${ }^{15-17}$ which dominate the behavior of semiconductors and insulators in the region of the interband transitions. In metals, the modifications of this structure due to the overlap of the Fermi energy with the electron bands might give even sharper singularities in the absorption. ${ }^{18}$

The basic virtue of the measurements to be discussed here is their ability to distinguish between singularities of different symmetry. The main difficulty in the analysis is that the "symmetry of a singularity" is quite frequently not well defined. For example, a structure in the absorption caused by an $M_{1}$ or an $M_{2}$ type singularity in the joint density of states is composed of transitions with $k$ vectors terminating on the optical energy surfaces $E(\mathrm{k})=E\left(M_{1}\right)$ and $E(\mathrm{k})=E\left(M_{2}\right)$, respectively. These surfaces stretch through the Brillouin zone, i.e., there is a whole range of transitions with different k vectors which contribute to the observed structure in the absorption. However, if the structure in the absorption is made up of transitions with wave vectors confined to a region close to a symmetry point $\mathrm{k}_{s}$ in k space, the structure will approximately respond to a perturbation as if it were composed of transitions with $\mathrm{k}_{s}$ only. We will refer to transitions of this kind as strongly localized transitions. Transitions arising from the $M_{1}$ and $M_{2}$ type singularities mentioned above are only moderately localized around the corresponding saddlepoints, and some transitions connected with singularities caused by the Fermi energy are not localized at all.

The experiments reported here were done with a technique similar to the one used for the alkali halides. ${ }^{10}$ They give the linear response of the optical constants to an arbitrary strain for photon energies between 1.5 and 5.5 eV . This information is used to determine the symmetry of strongly and moderately localized transitions; it also reveals which structure in the absorption

[^1]

Fig. 1. The mechanical oscillator. The extremal positions of the crystal are shown in the lower half of the figure. The oscillator is driven by an inhomogeneous ac magnetic field which acts on the small permanent magnets at the ends of the level arms.
is due to nonlocalized transitions. In addition, it is used to determine the deformation potentials of the observed transitions. The consistency of the assignment deduced from experiment with the calculated electronic structure of Cu is discussed. The effect of a general strain on the electronic structure is treated theoretically. The results obtained here are compared with those deduced from other experiments (e.g., photoemission ${ }^{19}$ ) and with theoretical calculations.

## EXPERIMENTAL METHOD

## Mechanical and Electronic Setup

An ac bending of rectangular single crystalline bars $\left(1 \times 3 \times 20 \mathrm{~mm}^{3}\right)$ was used to produce an ac strain at the surface of the crystal. The motion of the crystal is sketched in the lower half of Fig. 1. The two axes of rotation near the ends of the crystal (lower half) are realized by thin bronze bands, soldered to the two clamps which hold the crystal (upper half). Two lever arms are attached to the clamps, carrying small permanent magnets at their ends. The driving forces acting on these magnets were produced by the inhomogeneous ac magnetic field of two electromagnets. The frequency of the current passing through the electromagnets was tuned to the bending mode resonance frequency of the mechanical system.

There are also counterweights attached to the clamps (omitted in Fig. 1 for sake of clarity), which balance the mass of the permanent magnet, the lever arm, and the clamp. After removing the sample, the bronze bands will be a main axis of the moment of inertia for each assembly (magnet, lever arm, clamp, counterweight) individually. Thus, no forces are transmitted through the bronze bands. Otherwise, these forces might give an unwanted wavelength

[^2]modulation by coupling the mechanical vibration to the monochromator or give acoustical feedback by couplin, the vibration to the photomultiplier.

The reflected-light intensity, slightly modulated $\quad$. the strain-induced change of the reflectance, was de tected by a photomultiplier with quartz window (EMI 9558Q, Trialkali). The dc current of the multiplier d: not change when the wavelength setting of the mon, chromator was changed. This was achieved by using electronic feedback control of the photomultiplic: Thus the ac component of the anode current of $t:$ multiplier was proportional to $\Delta R / R$, the relative change of the reflectance. This component was nicu sured as a function of wavelength by means of a phase. sensitive detector and displayed on an $x-y$ recorde: The linearity of the system was checked with a photo diode; the ac to dc ratio was found to be correct to within $\pm 3 \%$.

## Strain Measurement

The strain at the surface of the sample will be tic same as that of a closed ring, formed by joining tic ends of a previously straight bar with rectangular cro... section, as shown in Fig. 2. This is true if the influenc of the clamps can be neglected. The cross section of t ring will generally be no longer rectangular. There ata two limiting cases for the stress tensor $\sigma$ and the stral tensor e at the middle line of the surface of the ris: One limit is approached if the radius $\rho_{1}$ and the thit. ness $d$ of the ring are large and the width $b$ is sm..." In this case, the stress tensor and the strain tensor tate the form

$$
\sigma^{\prime}=\left[\begin{array}{lll}
0 & & \\
& 0 & \\
& & \sigma_{z z}^{\prime}
\end{array}\right] ; \quad \mathrm{e}^{\prime}=\left[\begin{array}{lll}
e_{x x}^{\prime} & & \\
& e_{y y}^{\prime} & \\
& & e_{z z}^{\prime}
\end{array}\right]
$$

We tried to approach this limit in our measuremen' The quantitative conditions for the validity of Eqs. ! were found experimentally by measuring $\rho_{1}$ and $\rho$ : bent aluminum bars of various thicknesses and wid! The strain at the middle part of the surface is give" by $\left|e_{z z}{ }^{\prime}\right|=d / 2 \rho_{1}$ and $\left|e_{y y}{ }^{\prime}\right|=d / 2 \rho_{2}$. On the other har: ' the ratio $\left|e_{z z}{ }^{\prime} / e_{y y^{\prime}}\right|$ can be calculated using the stre strain relation and the form of the stress tensor. Us:


Fig. 2. A closed ring, formed by joining the ends of a previcus straight bar with rectangular cross section. The stress axis is !
hanical vibration to :. al feedback by coup olier.
slightly modulated he reflectance, was quartz window (E.)
nt of the multiplier h setting of the mo: as achieved by usin; the photomultip:
anode current of: $\Delta R / R$, the relat component was n .s. th by means of a phas d on an $x-y$ record checked with a pho: found to be correct

## ement

the sample will be t: formed by joining t with rectangular cre $s$ is true if the influend The cross section of $t$ ? rectangular. There a tensor $\boldsymbol{\sigma}$ and the stra: the surface of the rin radius $\rho_{1}$ and the thic: d the width $b$ is smal ad the strain tensor tal

$$
\left[\begin{array}{lll}
e_{x x}^{\prime} & & \\
& e_{y y}^{\prime} & \\
& & e_{z z}^{\prime}
\end{array}\right] \cdot(1
$$

$t$ in our measurements the validity of Eqs. (1 measuring $\rho_{1}$ and $\rho_{2}{ }^{\mathrm{C}}$ thicknesses and width of the surface is give $2 \rho_{2}$. On the other hand culated using the stres: the stress tensor. Usin:

ing the ends of a previous section. The stress axis is $z^{\prime}$.

1:2
icstress tensor given by (1), we found the agreement sureen the measured and calculated ratio to be better in $3 \%$, provided the condition $\left|e_{2 z}{ }^{\prime}\right| \leq 4 d^{2} / b^{2}$ was illed. In the optical measurements on Cu crystals, ical numbers were $\left|e_{z z}{ }^{\prime}\right|=4 \times 10^{-4}, 4 d^{2} / b^{2}=0.4$. Sus the above condition was always met.
in the actual measurements, the crystal forms a Eall segment of the ring shown in Fig. 2; the distoris produced by the clamps cannot always be necated. Measurements of $\rho_{1}$ and $\rho_{2}$ of large aluminum clamped at the ends in a way similar to that wown in Fig. 1 were carried out. The difference be$\therefore$ cen the calculated and the measured $\left|e_{z z}{ }^{\prime} / e_{y y}{ }^{\prime}\right|$ at c midpoint of the sample was again below $3 \%$, proad the free length of the sample (Fig. 1) was at ast twice its width. Typical values for the Cu crystals od in the optical experiments are $l=10 \mathrm{~mm}, b=3 \mathrm{~mm}$, c., this condition was also fulfilled.

Figure 3 shows the arrangement to determine the omponent $e_{z z}{ }^{\prime}$ of the strain tensor by measurement of the focal length of the cylindrical mirror, formed by the bent sample. The sample was oscillating, and the squency of the stroboscope was tuned close to the csonance frequency of the sample. The distance beween the sample and the image of the slit changed jcriodically with the difference frequency $\omega$ (strobosope) - $\omega$ (sample). The amplitude of the strain at the arface is given by

$$
\begin{equation*}
e_{z z}^{\prime}=\Delta a d\left(2 a_{0}\right)^{-2}\left\{1+\left[1+\left(\Delta a / a_{0}\right)^{2}\right]^{1 / 2}\right\}^{-1}, \tag{2}
\end{equation*}
$$

xhere $a_{0}$ is the position of the image for zero strain and $\Delta a$ is the difference in the position for maximum ex:ension and compression. The accuracy of this method increases with decreasing distance between lens and smple. It was about $\pm 5 \%$ for the geometry used bere. The components $e_{x x}{ }^{\prime}, e_{y y}{ }^{\prime}$ of the strain tensor are expressed in terms of the measured component $e_{z z}{ }^{\prime}$ by means of the stress-strain relation using the form 1) of the stress tensor. The elastic constants are taken :om Ref. 20. Because of the sample dimensions chosen, the errors in $e_{x x}{ }^{\prime}$ and $e_{y y}{ }^{\prime}$ due to deviations from (1) are smaller than $3 \%$. During the optical mea-


Fig. 3. The optical design which was used to determine the focal length of the cylindrical mirror formed by the bent sample.

[^3]

Fig. 4. The reflectance and $\epsilon_{2}$, the imaginary part of the dielectric constant of Cu at room temperature. The values determined by Ehrenreich and Phillipp (see Ref. 18) and by Beaglehole (see Ref. 22) are only shown if they differ by more than $2 \%$ from the values given in the present paper.
surement, the strain amplitude and phase was monitored by a pickup capacitor, consisting of one of the magnets at the ends of the lever arms (Fig. 1), moving against a fixed, insulated piece of sheet metal.

## Sample Preparation

The orientation of the samples cut from a single crystal was determined to within $\pm 1^{\circ}$ using Laue diagrams. The surface preparation consisted of grinding, mechanically polishing, and electropolishing ${ }^{21}$ the sample. The electropolishing was terminated by quickly rinsing in deionized water and alcohol. After taking the sample from the alcohol bath, the thin film of alcohol at the surface was immediately removed by a warm stream of air. The reflectance of a freshly prepared sample, measured within 10 min after the electropolishing, is given in Fig. 4. The growth of an oxide layer at the surface of the sample is responsible for the observed decrease in the reflectance with time. This decrease is most pronounced in the ultraviolet. We observed a $1 \%$ decrease at 5.5 eV within 1 h after the electropolishing.

Although the reflectance of our samples was measured in air, it deviates less than $1 \%$ from the values determined by Beaglehole, ${ }^{22}$ which were measured in a high vacuum after reducing the oxide layer at the surface. The only exception is the region around 4.3 eV . The resolution of the vacuum monochromator used by Beaglehole was not high enough to resolve finer details of the minimum at that energy ${ }^{23}$ (see Fig. 4). Thus the oxide layer on our sample modifies the reflectance not more than $1 \%$ between 1.5 and 5.5 eV . The reflectance given by Ehrenreich and Philipp ${ }^{18}$ is slightly lower

[^4]

Fig. 5. The optical path of the beam behind the monochromator.
than the one we found, indicating a slightly thicker oxide layer on their sample (Fig. 4).
Figure 4 also contains $\epsilon_{2}$, the imaginary part of the dielectric constant. It was obtained from a KramersKronig analysis. Between 5.5 and 25 eV , Beaglehole's reflectance values were used. Above 25 eV , the slope of the reflectance was adjusted to reproduce the absolute magnitude of $\epsilon_{2}$ given by Beaglehole. ${ }^{22}$ The slope of the edge in $\epsilon_{2}(\hbar \omega)$ at 4.3 eV is approximately the same for the function reported here and the one reported by Ehrenreich and Philipp. The edge determined by Beaglehole is somewhat flatter because of the less detailed structure in the reflectance at this energy.

## Optical Design and Error Signal

A major difficulty peculiar to modulation techniques such as described here and elsewhere ${ }^{8,9,11}$ arises from error signals which might, for example, be generated by the mechanical motion of the crystal. Such an error signal is difficult to separate from the true signal, because both have the same frequency and phase.
In designing the optical path behind the monochromator, we tried to minimize such error signals. One potential source of an unwanted intensity modulation is the large inhomogeneity of the photocathode, which tends to convert small lateral motions of the light beam into intensity modulations. The optical setup is shown in Fig. 5. The beam was focused on the sample and on the semitransparent cathode of the multiplier. The light spot on the cathode is the image of the corresponding point on the sample. It will not change its position, although the reflected beam might sweep over the toroidal mirror because of a motion of the sample or change its solid angle because of a change in the curvature of the sample. However, part of the light is transmitted by the cathode. It will partly reach the cathode again, being scattered by the dynodes. These scattered rays move slightly with respect to the cathode. They were found to be responsible for a substantial error signal, which was strongly wavelength-dependent owing to the wavelength-dependent transmission of the
cathode. This error signal was considerably reduced by placing a scattering plate 30 mm in front of the cathode. The plate consisted of a 0.1 -mm-thick quartz disk, roughened on both sides with mesh-1000 carborundum. The intensity loss due to this plate was about $40 \%$ at 5.5 eV and less at lower energies.

As discussed above, one source of the error signal will be the change of the angle $\varphi$ between the incident and the reflected beam due to the motion of the sample. This error signal was minimized by shifting the sample perpendicular to the beam in such a way that the beam was reflected at the dynamical center of the sample. In this position $\varphi$ no longer changes, although the crystal is vibrating (Fig. 1). During this adjustment the erro: signal itself served to monitor the position of the light spot on the sample with respect to the dynamical center. It was drastically enhanced for that purpose by maskin; down part of the reflected beam.
In addition to the sources of the error signal discussed above, the small motion of the sample normal to its surface needs to be considered. This will easily produce an intensity modulation if the optical quality of the surface is not excellent. The freshly electropolished surfaces were of high perfection; they did no: show any trace of light scattered at the surface. The measurements which will be discussed here were carricd out within 2 h after the electropolishing. They contained an error signal of only $2 \%$ of the maximum signal. About five days after the electropolishing one could see some weak scattering of light at the surface, probably due to an oxide layer of considerably large: thickness. The error signal was then of the same ordes of magnitude as the true signal, i.e., it had increase! by about a factor of 50 , compared to the one im. mediately after the electropolishing.
The response of the multiplier to small ac magnetic fields (as produced by the driving coils) is anothe: source of error signal. An effective magnetic shicld ing proved to be essential for the success of our measurements.

## Optical Measurements

The reflectance was measured at $4.5^{\circ}$ off normal in cidence. The difference between near normal and not mal incidence reflectance will be neglected in the analysis.
The reflectance of a bent sample contains two co: tributions. One comes from the discontinuity of $\epsilon$, complex dielectric constant at the surface. This con tribution is identical to that of a sample with honvo geneous strain equal to the strain at the surface of $t$ sample. Another contribution is due to the small vari. tion of $\epsilon$, caused by the variation of the strain in sample in the direction perpendicular to the surface The second contribution is normally several orders magnitude smaller than the first one, provided the change of $\epsilon$ over one wavelength is small compared to
considerably reduce: m in front of the cati, , -mm-thick quartz mesh-1000 carborund plate was about $40^{\circ}$ ries.
urce of the error s : . $\varphi$ between the ind:
he motion of the sar.;
d by shifting the sa:
ach a way that the be center of the sample. yes, although the cry: his adjustment the e: the position of the 1 , to the dynamical cer: that purpose by mask: 2.
of the error signal ic n of the sample nor: sidered. This will eat
on if the optical qual t. The freshly elect: perfection; they did : red at the surface. T. cussed here were carri tropolishing. They a
$2 \%$ of the maxim. the electropolishing ; of light at the surfa r of considerably lars then of the same or 1, i.e., it had increas apared to the one : ishing.
er to small ac magne: iving coils) is anot ective magnetic shic or the success of o:

## ements

d at $4.5^{\circ}$ off normal : ${ }^{2}$ near normal and n : be neglected in t:
nple contains two co: discontinuity of $\epsilon$, t: the surface. This $\mathrm{ce}^{-}$ a sample with hor in at the surface of $t$ due to the small var: on of the strain in t dicular to the surfac mally several orders rst one, provided t h is small compared

| Strain tensor | Type of strain | Stress axis $z^{\prime}$ | $\Delta \epsilon_{2}$ with respect to $x^{\prime}, y^{\prime}, z^{\prime}$ | Components $\Delta \epsilon_{2}$ and $\Delta R / R$ |
| :---: | :---: | :---: | :---: | :---: |
| $\left(\begin{array}{lll}1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1\end{array}\right) e / 3$ | Hydrostatic | None | $\left(\begin{array}{lll}1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1\end{array}\right) \Delta \epsilon_{2}$ | $\begin{aligned} & \Delta \epsilon_{2}=\frac{1}{3}\left(W_{11}+2 W_{12}\right) e \\ & \Delta R / R=\frac{1}{3}\left(Q_{11}+2 Q_{12}\right) e \end{aligned}$ |
| $\left(\begin{array}{lll}0 & 1 & 1 \\ 1 & 0 & 1 \\ 1 & 1 & 0\end{array}\right) e_{y z}$ | Trigonal | [111] | $\left(\begin{array}{lll}\Delta \epsilon_{2}{ }^{1} & 0 & 0 \\ 0 & \Delta \epsilon_{2}{ }^{1} & 0 \\ 0 & 0 & \Delta \epsilon_{2}{ }^{\prime \prime}\end{array}\right)$ | $\begin{aligned} & \Delta \epsilon_{2}{ }^{\mathrm{I}}=-2 \Delta \epsilon_{2}{ }^{1}=4 W_{44} e_{y z} \\ & \Delta R / R^{\mathrm{II}}=-2 \Delta R / R^{1}=4 Q_{44} e_{y z} \end{aligned}$ |
| $\left(\begin{array}{rrr}-\frac{1}{2} & 0 & 0 \\ 0 & -\frac{1}{2} & 0 \\ 0 & 0 & 1\end{array}\right) e_{z z}$ | Tetragonal | [001] | $\left(\begin{array}{lll}\boldsymbol{\Delta} \epsilon_{2}{ }^{1} & 0 & 0 \\ 0 & \Delta \epsilon_{2}{ }^{\perp} & 0 \\ 0 & 0 & \Delta \epsilon_{2}{ }^{\text {I }} \text { I }\end{array}\right)$ | $\begin{aligned} & \Delta \epsilon_{2}{ }^{I I}=-2 \Delta \epsilon_{2} \perp=\left(W_{11}-W_{12}\right) e_{z z} \\ & \Delta R / R^{\prime \prime}=-2 \Delta R / R^{\perp}=\left(Q_{11}-Q_{12}\right) e_{z z} \end{aligned}$ |

ve strain-induced change of $\epsilon$ at the surface. This adition was always fulfilled in our measurements. The second contribution will be neglected here.
The phase-sensitive detector was locked to the undamental frequency of the vibration. Thus, only tanges of the reflectance proportional to odd powers of rain were detected. Tuning to twice the frequency thich should pick up mostly the quadratic effect protaced a signal barely above the noise. Thus, only hanges linear in the strain components were detected 2 our measurements.

## EXPERIMENTAL RESULTS

## Symmetry Relations

The optical properties of a solid are determined by the complex second-rank dielectric tensor $\varepsilon$, which reluces to the unit tensor times the complex dielectric constant for cubic crystals, i.e., cubic crystals are pptically isotropic. A general strain applied to these rystals destroys the isotropy. Restricting the discussion to changes linear in the strain components, we may mite

$$
\begin{equation*}
\Delta \epsilon_{i j}=W_{v j m n} e_{m n} . \tag{3}
\end{equation*}
$$

Cu has the point symmetry $O_{h}$. In this case, Eq. (3) parallels the stress-strain relation ( $\Delta \varepsilon$ replaces the stress tensor, W the stiffness tensor), i.e., the fourthtank piezo-optical tensor W has three independent complex elements. ${ }^{8,9,11}$ We adopt the matrix notation used for the stress-strain relation (see, e.g., Ref. 24). Table I shows the resulting relations for $\varepsilon_{2}$, the imaginary part of the dielectric tensor. ( $W_{44}$ defined in Ref. 11 is four times that of Table I. Using the corresponding definition of the stiffness constant ${ }^{24}$ might help to avoid confusion, which frequently arose at that point in the past.) Selecting special geometries, namely the stress axis, the normal to the reflecting plane, and the polarization of the light parallel to the principal axes of $\Delta \varepsilon$ leads to8,9,11

$$
\begin{equation*}
\Delta R=\left(\partial R / \partial \epsilon_{1}\right) \Delta \epsilon_{1}+\left(\partial R / \partial \epsilon_{2}\right) \Delta \epsilon_{2}, \tag{4}
\end{equation*}
$$

where $\Delta \epsilon_{1}$ and $\Delta \epsilon_{2}$ are the appropriate eigenvalues of

[^5]$\Delta \varepsilon_{1}$ and $\Delta \varepsilon_{2}$. Thus we can define quantities $Q_{i j}$ (similar to $W_{i j}$ ) that describe the relative change of the reflectance. The definition of $Q_{i j}$ is also given in Table I.

## Measurements and Piezo-Optical Constants

Figure 6 contains the measurements of the relative change of the reflectance per strain along the stress axis for three different samples, the stress axes being parallel to [001], [111], and [110], respectively. The surface of the samples was the ( 110 ) plane in all cases. For each stress direction, the reflectance for light polarized parallel and perpendicular to the stress axis is given. The independent information contained in


Fig. 6. The relative change of the reflectance per unit strain along the stress axis at room temperature for Cu crystals with the stress axes [001], [111], and [110], and with the reflecting surface (1i0). The curves are given for light, plane polarized parallel and perpendicular to the stress axes.


Fig. 7. The relative change of the reflectance of Cu per strain for a change in volume $\left(Q_{11}+2 Q_{12}\right)$ and for trigonal $\left(Q_{44}\right)$ and tetragonal $\left(Q_{11}-Q_{12}\right)$ shear strain, evaluated from the six functions of Fig. 6 as indicated in Table II. The definition of the functions $Q_{i j}$ is given in Table I. The room-temperature reflectance of Cu is also included.
these six measured functions is that of three functions only, e.g., $Q_{11}+2 Q_{12}, Q_{44}$, and $Q_{11}-Q_{12}$ as given in Table I. There are in fact two measurements for each of the independent functions. Table II lists the measurements that were used to determine the $Q_{i j} ;$ Fig. 7 gives the three functions, together with the reflectance for zero strain. The deviations between points belonging to the same function but originating from different measurements is small; the error signal per strain along the stress axis, estimated from the remaining deviations is approximately $\pm 0.2$. This is about $2 \%$ of the maximum signal observed which is $Q_{11}+2 Q_{12}=9$ at $h \omega=4.15 \mathrm{eV}$.
Figure 8 contains the change of $\varepsilon_{2}$ resulting from the three independent symmetry distortions, expressed in terms of $W_{i j}$ (see Table I). The function $\epsilon_{2}$ for zero strain is also included. The quantities $W_{i j}$ were obtained from a Kramers-Kronig analysis of the $Q_{i j}$. The values for $Q_{i j}$ for $\hbar \omega<1.5 \mathrm{eV}$ and $\hbar \omega>5.5 \mathrm{eV}$ are not known. The functions $Q_{i j}$ are zero between 2 and 1.5 eV . The contribution of the free carrier absorption to $Q_{i j}$ remains small further in the infrared. ${ }^{11}$ We therefore used $Q_{i j}=0$ as the extrapolation below 1.5 eV . The functions $Q_{i j}$ are small at 5.5 eV , but they are not zero. There are probably nonzero values further in the ultraviolet. In doing the Kramers-Kronig transform, we joined the

Table II. Reduction of the measured relative change of reflectance to the piezo-optical constants $Q_{i j}$.

| $Q_{i j}$ |  | Determined from | $\begin{array}{c}\text { Stress } \\ \text { axis }\end{array}$ |
| :--- | :--- | :--- | :--- | \(\left.\begin{array}{c}Points <br>

Fig\end{array}\right]\)
functions $Q_{i j}$ smoothly with the zero line for $h \omega>5.5 \mathrm{c}$ In order to evaluate the error introduced by t : approximation, another Kramers-Kronig transform : done on $Q_{11}+2 Q_{12}$. This time the function was c trapolated to the minimum $Q_{11}+2 Q_{12}=-2$ at $6 \mathrm{eV}^{-}$a: joined smoothly with the zero line above 6.5 el . T! deviation in $W_{11}+2 W_{12}$ for the two extrapolations 5 at 5.5 eV ; this is $6 \%$ of the maximum value ( 81.5 $4.3 \mathrm{eV})$. The weighting function in the Kramers-Kron: integral assures that the error due to the extrapolatio decreases with decreasing energy. The error bars no. 5.5 eV in Fig. 8 give the deviation due to the extrap, tion discussed above, whereas the ones at 3.5 el the uncertainty produced by the error signal in $\Delta R R$


FIG. 8. The change of the imaginary part of the dielectric stant of Cu per strain for a change in volume $\left(W_{11}+2 W_{1}\right)$ for trigonal $\left(W_{44}\right)$ and tetragonal ( $W_{11}-W_{12}$ ) shear strain the imaginary part of the dielectric constant. The delinition the functions $W_{i j}$ is given in Table I.
neasured relative change of n-optical constants $Q_{i j}$.

| from | Stress axis | $\begin{gathered} \text { Points } \\ \mathrm{Fig}_{\mathrm{s}} \end{gathered}$ |
| :---: | :---: | :---: |
| nd $Q_{11}+2 Q_{12}$ | [111] | Circlea |
|  | [001] | Squa; |
|  | [111] | Circtes |
|  | [110] | Squar: |
|  | [001] | Circles |
| $Q_{12}$ | [110] | Squar |

the zero line for $h \omega>5.5 \mathrm{e}$ error introduced by $t$ mers-Kronig transform : time the function was $t$ $Q_{11}+2 Q_{12}=-2$ at 6 eV a: fero line above 6.5 eV . T $r$ the two extrapolations he maximum value (81.5 tion in the Kramers-Kron zor due to the extrapolati energy. The error bars ne fiation due to the extrapol. eas the ones at 3.5 eV gi: y the error signal in $\Delta R$;

sinary part of the dielectric co re in volume $\left(W_{11}+2 W_{12}\right)$ ar $4\left(W_{11}-W_{12}\right)$ shear strain ar I. constant. The definition

LE III. Symmetry rules for the optical transitions, considering the splitting of the $\mathbf{k}$ degeneracy only.

| , $\neq 0$; | $W_{11}-W_{12}=0$ | $\Lambda$ or $L$ transitions |
| :---: | :---: | :---: |
| $\cdots=0 ;$ | $W_{11}-W_{12} \neq 0$ | $\Delta$ or $X$ transitions |
| $\mathrm{S}_{1}$ | $W_{11}-W_{12} \neq 0$ | All transitions except $\Lambda, L, \Delta, X$ |

s spectral resolution given in Figs. 6-8 is the half. dth of atomic mercury lines, as recorded with our stical system.

## THEORETICAL ANALYSIS

## Symmetry Rules for Optical Transitions

Throughout the theoretical analysis we assume that ec are dealing with direct, k-conserving interband ansitions, i.e., that $\epsilon_{2}$ is dominated by this process. ie exclude the region below 2 eV where free carrier sorption is important.
There are two types of degeneracies in a solid, namely, c orbital degeneracy (e.g., $L_{3}$, twofold neglecting in) and the k degeneracy (e.g., the star of $\mathrm{k}_{L}$ contains ur equivalent vectors; any $L$ level will be fourfold sgenerate with respect to $\mathbf{k}$ ). Most of the orbital generacy is lifted already by spin-orbit interaction. we include the effect of strain and assume that the enter of gravity of the levels under consideration is zot changed by the strain, the total splitting will be siven by ${ }^{25}$

$$
\begin{equation*}
\Delta=\left(\Delta_{\text {spin orbit }}{ }^{2}+\Delta_{\text {strain }}{ }^{2}\right)^{1 / 2} . \tag{5}
\end{equation*}
$$

In Cu , the spin orbit splitting is about ten times the plitting produced by strain (the strain applied was about $5 \times 10^{-4}$ ). This means that the change of $\Delta$ is


Fig. 9. The band structure of Cu as calculated by Segall (see Kef. 13) and Burdick (see Ref. 14) using Chodorow's potential (see Ref. 26). The dashed curves are the free-electron eigenvalues. $F_{P}$ is the Fermi energy as calculated by Segall and Burdick and $F_{F^{0}}$ the Fermi energy calculated for the free-electron eigenvalues $t$ the $s p$ bands.

[^6]

Frg. 10. The insert (a) shows the change of the joint density of states in the neighborhood of an $M_{1}$ singularity produced by a rigid energy shift of the joint density of states; in part (b) of the figure the experimental function $\left(W_{11}-W_{12}\right)(\hbar \omega)^{2}$ is plotted.
second order in the strain and thus not detected in our measurements. We therefore must exclude the effect of a change of the spin-orbit splitting from our considerations.

Four effects may contribute to the observed $\Delta \epsilon_{2}$ in Cu , namely, the lifting of the k degeneracy, changes in the oscillator strength, changes in the joint density of states, and the splitting of the orbital degeneracy not lifted by spin-orbit interaction. The lifting of the $k$ degeneracy normally is the most important effect. We confine the discussion to this effect for the time being. The symmetry rules which follow are summarized in Table III. They were derived by considering the effect of trigonal and tetragonal shear strain on the set of originally equivalent $\mathbf{k}$ vectors (the star of $\mathbf{k}$ ). These rules depend only on the symmetry of the crystal for zero strain and on the symmetry of the distortion. Exceptions from these rules can arise only from accidental degeneracy, e.g., an $L$ and an $X$ transition at the same energy will produce a nonzero change in $\epsilon_{2}$ for both trigonal and tetragonal shear strain. It is largely due to these simple symmetry rules that the effect of shear strain on the optical constants is so powerful a method in analyzing the electronic structure of crystals.

Using Table III and the experimental results given in Fig. 8, we expect the edge at 2.1 eV to be caused by nonlocalized transitions, because shear strain gives only very small $\Delta \epsilon_{2}$ without pronounced symmetry behavior. Going from 2 to 4 eV , a $\Delta$ or $X$ transition must become increasingly important. A singularity in the joint density of states connected with these transitions is likely to occur at about 4.0 eV corresponding to the minimum in $W_{11}-W_{12}$ (see Fig. 8). Finally, there must be a pronounced singularity connected with $\Lambda$ or $L$ transitions at 4.3 eV , which is responsible for the large maximum in $W_{44}$.


Fig. 11. The energy contours of the surface $E(\mathrm{k})=E_{F}, L_{2}{ }^{\prime}$, $L_{1}-L_{2}{ }^{\prime}$, and $L_{1}-E_{F}$ around the $L$ point in a plane containing the $\Delta$ axis (left-hand part of the figure); the joint density of states near an $M_{2}$ singularity and the joint density of states at the same energy, but modified by the Fermi energy (right-hand part).

## Comparison Experiment-Band Structure

The energy bands of Cu , as calculated by Segall ${ }^{13}$ and Burdick ${ }^{14}$ using Chodorow's ${ }^{26}$ potential, are shown in Fig. 9. The free-electron eigenvalues are also indicated, together with the Fermi energy for the empty and the actual lattice. We refer to this band structure in the following.
The $2.1-\mathrm{eV}$ edge in $\epsilon_{2}$ is known to be due to transitions from the top of the $d$ bands to the Fermi surface (FS). ${ }^{18,27}$ The experimentally observed energy is well reproduced by the $E(\mathrm{k})$. These transitions will start at $Q$ near $L$, but at slightly higher energies various parts of the Brillouin zone (BZ) will contribute. This is consistent with the observed lack of response to shear strain.
The only transition at about 4 eV with k parallel to [001] which is connected with a singularity in the joint density of states is $X_{5} \rightarrow X_{4}^{\prime}$. The energy difference is 4.0 eV , which is 0.1 eV larger than the position of the minimum in $W_{11}-W_{12}$. The structure at 4.3 eV must be due to transitions near $L$, since there are no $\Lambda$ transitions with comparable energies. The FS $\rightarrow L_{1}$ transition is closest in energy, although the transitions $L_{3}{ }^{2} \rightarrow \mathrm{FS}$ and $L_{1}{ }^{d} \rightarrow \mathrm{FS}$ are also not far removed (the superscripts $l=$ lower and $u=$ upper distinguished the two $L_{3}$ levels in the $d$ bands).

## Line-Shape Analysis

The $X_{5} \rightarrow X_{4}{ }^{\prime}$ transition is related to an $M_{1}$ critical point (c.p.) in the joint density of states. The contributions at lower energies, originating from $\Delta_{5} \rightarrow \Delta_{1}$, are truncated by the FS below 2.1 eV . The contributions $J_{\Delta X}$ to the total joint density of states $J$ are shown schematically in Fig. 10(a). The change in $J$ produced by a rigid shift in energy is shown in the lower part. For constant matrix elements, $J$ will be proportional

[^7]to $(\hbar \omega)^{2} \epsilon_{2} .{ }^{28}$ Even for changing matrix elements expect $(\hbar \omega)^{2} \epsilon_{2}$ to follow more closely the actual pendence of $J$ than $\epsilon_{2}$ itself. Figure 10(b) gives function $(\hbar \omega)^{2}\left(W_{11}-W_{12}\right)$, which is to be compared the predicted change of Fig. 10(a). The agreem shows that the functional dependence of $W_{11}-W_{12}$ consistent with that predicted by the above assignme:
Considering the 4.3 eV structure in $W_{44}$, we m compare $\epsilon_{2}$ and $J$ directly, because the structure confined to a narrow energy region. The main differet between the $L^{d} \rightarrow \mathrm{FS}$ ( $M_{1}$ c.p.) and the $\mathrm{FS} \rightarrow L_{1}$ tran tions ( $M_{2}$ c.p.) is the way the original contributions the joint density of states are truncated by the FS. Fig. 11, the lines of constant energy are shown for : $L_{2}{ }^{\prime}$ band and for the difference $L_{1}-L_{2}{ }^{\prime}$ in a plane cos taining the $\Lambda$ axis. The joint density of states arour the $M_{2}$ c.p. is modified as shown in Fig. 11. The ener, difference $E_{N}=E_{F}-L_{2}{ }^{\prime}$ is small compared to $L_{1}-1$. (the symmetry labels such as $L_{1}$ are also used to den) the corresponding eigenvalues for typographical a venience). In this case, the variation of $J$ in the regi $L_{1}-E_{P} \leq h \omega \leq L_{1}-L_{2}{ }^{\prime}$ is given by
$$
J(\hbar \omega)=4 \pi \Omega(2 \pi)^{-3} m_{11}^{1 / 2} m_{\perp}\left(\hbar \omega-L_{1}+E_{F}\right)^{1 / 2}
$$

In the derivation of Eq. (6) the neck was approximat by a cylinder. The slope of $J$ as given by Eq. (6) largest for $\hbar \omega$ slightly larger than $L_{1}-E_{F}$. The slog at $\hbar \omega=L_{1}-E_{F}$ will be finite because of lifetime broad ing. The largest values of $W_{i j}$ will thus occur at slightly larger than $L_{1}-E_{F}$, provided $W_{i j}$ is caused ! an energy shift of the edge in $\epsilon_{2}$. Figure 11 and Eq. show that the FS $\rightarrow L_{1}$ transitions are strongly locali: around the $L$ point; all k vectors terminate in a reg enclosed by the neck.

The k vectors of transitions $L^{d} \rightarrow \mathrm{FS}$ termin outside the neck, i.e., these transitions are not localli: According to Table III, we expect a change in $\epsilon$. both trigonal and tetragonal shear strain, and we e. this change to be small. The experiments show a w large $W_{44}$. The small $W_{11}-W_{12}$ at the same enery. probably left from the $X_{5} \rightarrow X_{4}^{\prime}$ transitions near (this is the accidental degeneracy mentioned abo: Thus the structure at 4.3 eV is most probably dur the strongly localized FS $\rightarrow L_{1}$ transitions.
The values of the square of the momentum mis elements $M$ for the transitions of interest herc. calculated by Mueller, ${ }^{29}$ are given in Table IV. oscillator strength for the $L_{2}{ }^{\prime} \rightarrow L_{1}$ transition is larger than that for transitions originating from $d!$ states. In fact, Mueller and Phillips ${ }^{29}$ found that al $40 \%$ of the total $\epsilon_{2}$ around 4.5 eV is due to the duction-band-conduction-band transitions. The act value might be somewhat lower due to lifetime bro ening, which tends to reduce the height of the st structure in $\epsilon_{2}$, originating from these transitions (1

[^8]pre closely the actuas f. Figure 10(b) gives nich is to be compared g. 10(a). The agree ependence of $W_{11}-1 ;$ i by the above assignt: tructure in $W_{44}$, we : because the structure egion. The main difiere: 2) and the FS $\rightarrow L_{1}$ tra e original contributions e truncated by the Fs. energy are shown fo: ce $L_{1}-L_{2}^{\prime}$ in a plane i density of states atc. wn in Fig. 11. The en nall compared to $L_{1-}$ $L_{1}$ are also used to de: es for typographical c ariation of $J$ in the re. n by
$n_{1}\left(\hbar \omega-L_{1}+E_{F}\right)^{1 / 2}$.
re neck was approxima $J$ as given by Eq. ( 6 than $L_{1}-E_{F}$. The s! cause of lifetime broal ${ }_{i j}$ will thus occur at rovided $W_{i j}$ is caused $\epsilon_{2}$. Figure 11 and Eq. ions are strongly locali cors terminate in a re.
ons $L^{d} \rightarrow \mathrm{FS}$ termin asitions are not localiz xpect a change in $\epsilon$. pear strain, and we exy experiments show a ${ }_{12}$ at the same energ: $X_{4}^{\prime}$ transitions near racy mentioned abo: is most probably due -1 transitions.
$i$ the momentum mat: ons of interest here, given in Table IV. ' $\rightarrow L_{1}$ transition is m ! originating from $d b$ tillips ${ }^{29}$ found that ab 3 eV is due to the transitions. The act ir due to lifetime bro the height of the sh: a these transitions ( $F$
(1958).

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Table IV. Transition matrix elements in (Ry) for selected transitions.

| [ransition ${ }^{\text {s }}$ | $L_{2}{ }^{\prime} \rightarrow L_{1}$ | $L_{1}{ }^{d} \rightarrow L_{2}{ }^{\prime}$ | $L_{3}{ }^{\text {b }} \rightarrow L_{2}{ }^{\prime}$ | $X_{5} \rightarrow X_{4}^{\prime}$ |
| :---: | :---: | :---: | :---: | :---: |
| $2 P_{\text {Pij }}{ }^{2} / m$ | 3.17 | 0.533 | 0.015 | 0.250 |

-The matrix elements are calculated using the eigenvalues given in (f. It [F. M. Mueller (private communication)].
(1). From the experimental $\epsilon_{2}$ we estimate a total stribution of about $30 \%$, extrapolating the contribu$n$ of the background below 4.1 eV to about 4.65 eV . The high percentage of $L_{2}^{\prime} \rightarrow L_{1}$ transitions as calcuated from theory is consistent with the pronounced arge in the experimental $\epsilon_{2}$ and with the large $W_{44}$ as well. This leads again to the conclusion that the obcwed structure in $\epsilon^{2}$ and $\Delta \epsilon_{2}$ at 4.3 eV is caused by the $: S \rightarrow L_{1}$ transition.
Another striking feature of the functions $W_{i j}$ is the rastly different magnitude of $W_{44}$ and $W_{11}-W_{12}$. The -aximum $\Delta \epsilon_{2}$ observed for trigonal shear strain is nine times the corresponding value for tetragonal shear train (the amount of the strain being the same). This is artly due to the different degree of localization in $k$ pace discussed above and partly to the difference in e oscillator strength (Table IV). The small oscillator trength for $X_{5} \rightarrow X_{4}^{\prime}$ as compared with the one for $L_{2}^{\prime} \rightarrow L_{1}$ suggests that there is no pronounced structure $\rightarrow \epsilon_{2}$ around 4.0 eV , and indeed the experimental curve s nearly flat in this region. However, we believe to have esolved a tiny hump in our room-temperature measurewents of $\epsilon_{2}$, as shown in Fig. 12. The reflectance at quid He temperatures ${ }^{30}$ shows a well-resolved structure it about the same energy. The transition does show up dearly as a minimum in $W_{11}-W_{12}$ at room temperature. The hydrostatic change ( $W_{11}+2 W_{12}$ ) and the change with trigonal shear strain ( $W_{44}$ ) have the same shape setween 4 and 4.5 eV . The position of the maximum is 4.3 eV in both cases. This suggests that both effects se due to the FS $\rightarrow L_{1}$ transition. The two functions liffer between 4.5 and 5 eV , where $W_{11}+2 W_{12}$ exhibits in additional shoulder around 4.8 eV , whereas $W_{44}$ approaches zero rapidly. This behavior can be explained assuming transitions from the bottom of the $d$ tands to the FS. As in the case of the $2.1-\mathrm{eV}$ edge (where the top of the $d$ bands provides the initial states), these ransitions originate from general points of the BZ. This explains the lack of response to shear strain. The transitions will of course change under hydrostatic train. The situation is equivalent to the one at the $\because 1-\mathrm{eV}$ edge, where only hydrostatic strain produces a significant change in $\epsilon_{2}$.

## Experimental Deformation Potentials

The assignment of the structure observed in $W_{i j}$ and $\epsilon_{2}$ has been established in the preceding sections. This information can be used to calculate the deforma-

[^9]

Fig. 12. A blow-up of the imaginary part of the dielectric constant of Cu at room temperature around 4 eV , showing weak structure slightly below 4 eV . The slope of the edge at 4.3 eV and the slope of the background which were used to calculate the deformation potentials of the $E_{F} \rightarrow L_{1}$ transition are also included.
tion potentials of the corresponding transitions from the experiments, i.e., the difference in the deformation potentials of the final and the initial state. Additional knowledge is required to do so, namely, the slope $d \epsilon_{2} / d(\hbar \omega)$ of that part of $\epsilon_{2}$ which is responsible for the observed structure in $W_{i j}$ and the selection rules (required for the shear-strain coefficients only). Furthermore, it must be possible to separate that part of $W_{i j}$ which is due to a change of the energy levels from the ones due to modifications of the transition matrix elements $M$ and of the density of states $J$.

The slope of the edge at 2.1 eV is large; modifications due to a background of transitions other than $L_{3}{ }^{u} \rightarrow \mathrm{FS}$ (e.g., free carrier absorption) will be small. The selection rules are not needed because only hydrostatic strain produces a pronounced change in $\epsilon_{2}$. The changes in $M$ and $J$ produced by a hydrostatic strain will be much smaller than the ones produced by shear strain, in which case they are required by symmetry. ${ }^{7}$ Only $W_{11}+2 W_{12}$ is large at this edge, which shows that changes of $M$ and $J$ contribute very little to $W_{11}+2 W_{12}$. The deformation potential will be given quite accurately by the maximum value of $W_{11}+2 W_{12}$ and by the uncorrected slope of $\epsilon_{2}$.

As discussed above, the $2.1-\mathrm{eV}$ edge is due to nonlocalized transitions; the transitions with lowest energy have $\mathbf{k}$ vectors terminating just outside the neck, but at slightly higher energies transitions with $\mathbf{k}$ vectors located in other parts of the BZ will contribute. The deformation potential determined from the energy shift of the edge will be an average over the deformation potentials of all transitions which contribute. However, the top of the $d$ bands is rather flat, particularly the portion $L_{3}{ }^{u}-Q_{+}$, and it will remain flat if the volume of the crystal is changed. Thus the deformation potentials of transitions contributing to the edge differ only slightly from each other. We therefore no

Table V. Matrix elements and strain coefficient of matrix elements which were used to calculate the deformation potentials at $L$.

| Orthogonality matrix element | Tight-binding integrals | Pseudopotential | Hybridization | Zero of $d$ bands above $\mathrm{r}_{\mathrm{t}}$ |
| :---: | :---: | :---: | :---: | :---: |
| $b_{d}=-0.366$ | $\begin{aligned} & \sigma=-0.332 \mathrm{eV} \\ & \pi=+0.180 \mathrm{eV} \\ & \delta=-0.027 \mathrm{eV} \end{aligned}$ | $V_{111}=0.29 \mathrm{eV}$ | $H_{\varphi d}=1.32 \mathrm{eV}$ | $E_{d}=5.75 \mathrm{eV}$ |
| $\begin{aligned} & \partial b_{d} / \partial e_{y_{2}}=0.73 \Delta \\ & k \partial\left(\ln b_{d}\right) / \partial(3 k)=0.332 \end{aligned}$ | $R \partial(\ln \sigma) / \partial R=-5.5^{\mathrm{b}}$ $R \partial(\ln \pi) / \partial R=-6.9$ $R \partial(\ln \delta) / \partial R=-8.0$ | $\begin{aligned} & \partial V_{111} / \partial c_{y}=-3.85 \mathrm{eV}^{\mathrm{s}} \\ & \partial V_{111} / \partial c=-0.93 \mathrm{eV}^{\mathrm{a}} \end{aligned}$ | d | e |

longer distinguish between the energy shift of the $2.1-\mathrm{eV}$ edge and the change of the $E_{F}-L_{3}{ }^{u}$ separation. The numerical value is $\partial\left(E_{F}-L_{3}{ }^{u}\right) / \partial e=-(1.1 \pm 0.1) \mathrm{eV}$, where $e=\Delta V / V$ denotes the relative change of the volume.

The $X_{5} \rightarrow X_{4}^{\prime}$ transition contributes only a small fraction of the total $\epsilon_{2}$ at 3.9 eV . It is impossible to get reliable values of $d \epsilon_{2} / d(h \omega)$ appropriate to this fraction of $\epsilon_{2}$. We do not attempt to calculate the shear-strain deformation potential of this transition; instead, we simply show that it will produce a negative $W_{11}-W_{12}$ below the energy of the critical point. The level $X_{4}{ }^{\prime}$ has free-electron character; it does not interact with the $d$ bands because of symmetry (Fig. 9). Its eigenvalue is $k^{2}$ ( $\mathrm{k}=\mathrm{X}$, in atomic units), neglecting a small pseudopotential form factor. The shear coefficient for $\mathbf{k}$ perpendicular to $z$ (stress axis, see Table I) is $\partial\left(\ln k^{2}\right) /$ $\partial e_{z 2}=+1$. The shear coefficient of the $X_{5}$ level, which has tight binding character, will be small compared to that of $k^{2}$. Thus the sign of the change in $X_{4}^{\prime}-X_{5}$ is given by the change of $k^{2}$. For light polarized parallel to $z$ only those transitions of $X_{5} \rightarrow X_{4}^{\prime}$ with $k$ perpendicular to $z$ contribute according to the selection rules (these are strictly valid only for the $X$ point and zero spin-orbit splitting, but they will hold approximately). Thus, the $M_{1}$ c.p. shifts to higher energies for positive $e_{z z}$, producing negative values for $W_{11}-W_{12}$ below 4.0 eV , as observed.

The FS $\rightarrow L_{1}$ transition has been found to be responsible, for the large values of $W_{44}$ and $W_{11}+2 W_{12}$ at 4.3 eV and for the edge in $\epsilon_{2}$ at this energy. Because .of the strong localization of this transition the deformation potentials derived from $W_{i j}$ will be close to those of the transition with $\mathrm{k}=\mathrm{L}$. Transitions connected with $M_{1}$ and $M_{2}$ singularities in $J$ which are not modified by the Fermi energy will behave differently, because they are only moderately localized, as discussed in the Introduction. The deformation potentials of transitions with different k will generally be different. Indeed, Brust and Liu ${ }^{31}$ have shown recently that the deformation potential of the transition with k of the saddlepoint and the energy shift per strain of the corresponding structure in the optical spectrum can differ significantly.

The background slope of $\epsilon_{2}$ at 4.3 eV due to transitions other than $\mathrm{FS} \rightarrow L_{1}$ cannot be determined

[^10]rigorously. We use the slope of $\epsilon_{2}$ at 4.05 eV , which is $-0.5 / \mathrm{eV}$ (Fig. 12). The similarity of $W_{11}+2 W_{12}$ and $W_{44}$ around 4.3 eV shows that changes of $M$ and $J$ which can be large for shear strain only do not contribute significantly to $W_{44}$. Furthermore, $W_{i j}$ has its maximum where the slope of $\epsilon_{2}$ is largest and where the contribution of this transition to the total $\epsilon_{2}$ is still small. If present, changes of $J$ and $M$ would have the largest effect on $W_{44}$ at the maximum contribution of $L_{2}{ }^{\prime} \rightarrow I_{1}$ to $\epsilon_{2}$. Thus neglecting changes of $M$ and $J$ is justified here. This also justifies the analysis of the previous sections, where we considered the effect of shear strain on the k degeneracy only.

Without spin, the $L_{2}{ }^{\prime} \rightarrow L_{1}$ selection rules are $M_{z^{\prime}} \neq 0, M_{x^{\prime}}=M_{y^{\prime}}=0$, where $\mathrm{k}=\mathrm{L}$ is parallel to $z^{\prime}\left(z^{\prime}=\right.$ stress axis, Table I). With spin, these rules will still be approximately valid $\left(\left|M_{z^{\prime}}\right|^{2} \ll\left|M_{x^{\prime}}\right|^{2}\right)$. The selection rules for $\mathrm{k} \neq \mathrm{L}$ will be different from the ones given above, even without spin. The strong localization of the transitions in k space assures that this deviation is small. The shear coefficient of the transition will bc calculated neglecting the deviations from the selectio: rules given above.

The deformation potentials determined from es periment and evaluated using the assumption dis cussed above are $\partial\left(L_{1}-E_{F}\right) / \partial e=(-9.6 \pm 1.5) \mathrm{eV}$ and $\partial\left(L_{1}-E_{F}\right) / \partial e_{y z}=(-72 \pm 12) \mathrm{eV}$ for k parallel [11i] The largest uncertainty in these coefficients is due to the background slope in $\epsilon_{2}$ (the values given earlier ${ }^{\text {t }}$ are $8 \%$ higher because the background slope used wa. $-0.3 / \mathrm{eV}$ instead of $-0.5 / \mathrm{eV}$ used here).

## Theory of the Deformation Potentials at $L$

The theoretical estimate of the deformation potentials of the FS $\rightarrow L_{1}$ transitions given earlier ${ }^{12}$ neglecte! the plane-wave admixture to the wave function of th. $d$ state $L_{1 d}$, i.e., $d$-sp hybridization. The treatment ou: lined below includes the hybridization.

We use the model Hamiltonian developed fs Saffren, ${ }^{32}$ Ehrenreich and co-workers, ${ }^{33}$ and Muellot ${ }^{3}$
${ }^{32}$ M. Saffren, in The Fermi Surface, edited by W. A. Harri and M. B. Webb (John Wiley \& Sons, Inc., New York, 1\% p. 341.
${ }_{33} \mathrm{~L}$. Hodges and H. Ehrenreich, Phys. Letters 10, 203 ( $191^{\circ}$, L. Hodges, H. Ehrenreich, and N. D. Lang, Phys. Rev. 1 505 (1966).
${ }_{34}$ F. M. Mueller, Phys. Rev. 153, 659 (1967).

| ieformation potentials at $L$. |  |
| :---: | :---: |
| zation | Zero of bands above: |
| . 32 eV | $E_{d}=5.75 \mathrm{sil}$ |
|  | e |

a the relative change of the vel:
of $\epsilon_{2}$ at 4.05 eV , whict. ilarity of $W_{11}+2 W_{12}$. changes of $M$ and $J$ whi 2 only do not contrib. core, $W_{i j}$ has its maximu $t$ and where the contri: total $\epsilon_{2}$ is still small. would have the large contribution of $L_{2}{ }^{\prime} \rightarrow$ es of $M$ and $J$ is justif analysis of the previo the effect of shear stri:
, $L_{1}$ selection rules a re $\mathbf{k}=\mathbf{L}$ is parallel With spin, these rules w $\left(\left|M_{z^{\prime}}\right|^{2} \ll\left|M_{x^{\prime}}\right|^{2}\right)$. T je different from the or n. The strong localizatic ssures that this deviatic of the transition will iations from the selecti

Is determined from e ing the assumption d: $\partial c=(-9.6 \pm 1.5) \mathrm{eV}$ ar eV for $\mathbf{k}$ parallel [111] lese coefficients is due the values given earlie: ckground slope used wa used here).

## ion Potentials at $L$

the deformation poter: s given earlier ${ }^{12}$ neglecte the wave function of $t$ t tion. The treatment ou' idization.
uiltonian developed $b$ workers, ${ }^{33}$ and Mueller uce, edited by W. A. Harris pons, Inc., New York, 1960
Phys. Letters 10, 203 (1965, D. Lang, Phys. Rev. 15:

659 (1967).

Table VI. Deformation potentials (in eV) of the transitions at $L$.

| Normation <br> stentials | Experiment |  | Theory |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | Present paper | Zallen ${ }^{\text {a }}$ | Present paper | $\mathrm{DFJ}^{\mathrm{b}}$ | Jacobs ${ }^{\text {e }}$ |
| $\begin{array}{r} \left.-E_{p}\right) / \partial e_{y_{z}} \\ \left.-E_{P}\right) / \partial^{d} \\ \left.-L_{a}^{u}\right) / \partial e \end{array}$ | $\begin{aligned} & -72 \pm 12 \\ & =9.6 \pm 1.5 \\ & -1.1 \pm 0.1 \end{aligned}$ | $9.7 \pm 2.0$ <br> Absolute value $<1.3$ | $3^{-56}$ | $\begin{aligned} & -5.1 \\ & -0.8 \end{aligned}$ |  |
| $\left.\therefore \therefore-L_{3}{ }^{*}\right) / \partial e$ |  |  |  | -5.9 | -4.1 |

- Reference 47.

Reterence 43.

- Reference 48.
$\rightarrow,=\Delta V / V$ is the relative change of the volume $V$.
the form given by Cohen and Mueller. ${ }^{35}$ Using symctrized plane waves as well as symmetrized tightding functions, we can write down the eigenvalues of $\vdots$ and of $L_{3}{ }^{u, l}$ immediately:

$$
\begin{align*}
L_{2}{ }^{\prime} & =k^{2}-V_{111}  \tag{7}\\
L_{3}{ }^{l, u} & =E_{d}+\pi-\delta \pm\left[(\pi-\delta)^{2}+4.5(-\sigma+\delta)^{2}\right]^{1 / 2} \tag{8}
\end{align*}
$$

the vector k is that of the $L$ point, $V_{111}$ is a pseudovential form factor, $E_{d}$ gives the position of the $d$ unds above $\Gamma_{1}$, and $\sigma \equiv(d d \sigma), \pi \equiv(d d \pi)$, and $\delta \equiv(d d \delta)$ tee the two-center tight-binding integrals defined by Iter and Koster. ${ }^{36}$ The two $L_{1}$ levels are obtained om the secular equation

$$
\left|\begin{array}{ll}
H_{\Phi \Phi}-E & H_{\Phi d}  \tag{9}\\
H_{d \Phi} & H_{d d}-E
\end{array}\right|=0 .
$$

The function $d$ is a tight-binding Bloch sum symetrized to $L_{1}$ and $\Phi$ is a plane wave symmetrized to t and orthogonalized to $d$,

$$
\begin{equation*}
\Phi=\left(\varphi-b_{d} d\right) / C . \tag{10}
\end{equation*}
$$

The abbreviations used in Eq. (10) are

$$
\begin{align*}
\varphi & =(2 / V)^{1 / 2} \cos (\mathbf{k} \cdot \mathbf{r}),  \tag{11}\\
b_{d} & =\langle\varphi \mid d\rangle,  \tag{12}\\
C^{2} & =1-b_{d}{ }^{2} . \tag{13}
\end{align*}
$$

The matrix elements of Eq. (9) are

$$
\begin{align*}
& H_{d d}=E_{d}-4(\pi-\delta),  \tag{14}\\
& H_{\Phi d}=\left(H_{\varphi d}-b_{d} H_{d d}\right) / C  \tag{15}\\
& H_{\Phi \Phi}=\left(k^{2}+V_{111}+V_{\varphi \varphi}(2)+b_{d}^{2} H_{d d}-2 b_{d} H_{\varphi d}\right) / C^{2} . \tag{16}
\end{align*}
$$

We calculated $b_{d}$ and the tight-binding integrals using the atomic wave function and the atomic potential alculated by Hartree and Hartree ${ }^{37}$ and parametrized

[^11]

Fig. 13. The dependence of the shear strain deformation potential $\partial L_{1} / \partial e_{y z}$ on the strain coefficient of the orthogonality integral $b_{d}$ [part (a) of the figure] and on the strain coefficient of the hybridization $H_{\varphi d}$ [part (b) of the figure]. The value $\partial b_{d} /$ $\partial e_{\nu z}=0.73$ was calculated using atomic $d$ functions.
by Fletcher and Wohlfahrth. ${ }^{38}$ The numerical values are given in Table V. The tight binding integrals agree with those calculated by Fletcher and Wohlfahrth. The value of the orthogonalization integral $b_{d}$ given by Mueller ${ }^{34}$ is $16 \%$ lower than the one reported here.
A first-principles calculation of the quantities $E_{d}$, $H_{\varphi d}$, and $\Delta V_{\varphi \varphi}{ }^{(2)}$ is extremely difficult and will not be attempted here. Instead, we determine them from the eigenvalues of Fig. 9, ${ }^{13,14}$ using the calculated values of $b_{d}$ and of the tight-binding integrals. In particular, the value of the hybridization integral $H_{\varphi d}$ is evaluated from the difference between $H_{d d}$ (the eigenvalue of $L_{1}{ }^{d}$, neglecting hybridization) and $L_{1}{ }^{d} . E_{d}$ is calculated from $L_{3}-\Gamma_{1}$ using Eq. (8). ( $L_{3}{ }^{u}-L_{3}{ }^{l}$ given by this equation agrees with the value taken from Fig. 9. One would expect this, since these bands have no interaction with the $s p$ bands.) The form factor $V_{111}$ given by Eq. (7) is also taken from the calculated band structure.
$\Delta V_{\varphi \varphi}{ }^{(2)}$ is the matrix element of the crystal potential, calculated with the $l=2$ component of $\varphi$. It was introduced in the model Hamiltonian ${ }^{35}$ following a suggestion by Heine. ${ }^{39}$ Its numerical value (calculated using the $L_{1}-L_{1}{ }^{d}$ gap of Fig. 9) is small, namely, -0.75 eV . Neglecting $\Delta V_{\varphi \varphi}{ }^{(2)}$ gives $L_{1}-L_{1}{ }^{d}=9.85 \mathrm{eV}$ using Eq. (9), which is only 0.60 eV higher than the value of Fig. 9. $\Delta V_{\varphi \varphi}{ }^{(2)}$ will be neglected in the following. The zero-strain values of $V_{111}, H_{\varphi d}$, and $E_{d}$ are listed in Table V.
The tight-binding parameters for changed nearestneighbor distances were calculated in the same way as for the distance in the unstrained crystal. For trigonal distortion (Table I) and levels with k parallel to [111], the strain coefficient of $H_{d d}$ is ( $R$ is the nearest-neighbor

[^12]

Fig. 14. The dependence of the volume deformation potential $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial e$ on the strain coefficients of $b_{d}$ and $H_{\varphi d}$ plotted in a way similar to that of Fig. 13. In addition, the dependence on the volume coefficient of $E_{d}$ is given [dashed curve in part (b) of the figure].
distance)

$$
\begin{align*}
\partial H_{d d} / \partial e_{y z}=-[12 \sigma-8 \pi & +4 \delta \\
& +R \partial(3 \sigma+4 \pi+5 \delta) / \partial R] . \tag{17}
\end{align*}
$$

The strain dependence of $V_{111}$ is calculated using a simple model potential. ${ }^{40}$ It is constructed from a bare ion potential which is zero inside the core region ( $r<r_{c}$ ) and equal to the Coulomb potential of a single positive charge outside ( $-2 / r$ in atomic units). Its Fourier transform is divided by $\epsilon_{q}$, the static Hartree dielectric function for free electrons, ${ }^{41}$ to give the form factor

$$
\begin{equation*}
V_{q}=-8\left(\cos q r_{c}\right) /\left(\epsilon_{q} \Omega q^{2}\right), \tag{18}
\end{equation*}
$$

where $\Omega$ is the volume of the unit cell. The value of $r_{c}$ ( 0.23 of the nearest-neighbor distance) is determined by $V_{11}$ of Table $V$; it is regarded as a constant in calculating the strain coefficients of $V_{111}$ from Eq. (18). The values of the overlap integral $b_{d}$ for the deformed crystal are calculated in the same way as $b_{d}$ for zero strain. All strain coefficients discussed above are listed in Table V.

The calculation of the deformation potentials requires additional knowledge, namely, the strain coefficients of $H_{\varphi d}, E_{d}$, and $E_{F}$. The effect of pure trigonal shear strain will be considered first. In this case, there is no change of $E_{d}$ and $E_{F}$ linear in the strain components: The center of gravity of originally degenerate levels remains unchanged to first order; this causes $E_{d}$ and $E_{F}$ to be constant, too. As a consequence,

$$
\begin{equation*}
\partial\left(L_{1}-E_{P}\right) / \partial e_{y_{2}}=\partial L_{1} / \partial e_{y z} . \tag{19}
\end{equation*}
$$

A rigorous calculation of $\partial H_{\varphi d} / \partial e_{y z}$ would be even more difficult than the calculation of $H_{\varphi d}$ itself. We therefore simply assume the relative change of $b_{d}$ and $H_{\varphi d}$ to

[^13]Table VII. Volume coefficients of the Fermi energy and of th, position of the $d$ bands.

| Volume <br> coefficients | Present <br> paper | Derived from <br> dHvA $^{\mathrm{b}}$ | DFJ $^{\mathrm{c}}$ |
| :---: | :---: | :---: | :---: |
| $\partial\left(\ln E_{d}\right) / \partial e$ | $-1.2 \pm 0.5$ |  | -0.85 |
| $\partial\left(\ln E_{F}\right) / \partial e$ | $-1.1 \pm 0.3$ | -0.73 | -0.86 |

$V_{6}{ }^{2} \Gamma_{1}$ is the zero of energy and $e=\Delta V / V$ is the relative change of the volums:
$V$.
b Reference 50.

- Reference 43.
be identical,

$$
\begin{equation*}
\partial\left(\ln H_{\varphi d}\right) / \partial e_{y z}=\partial\left(\ln b_{d}\right) / \partial e_{y z} . \tag{20}
\end{equation*}
$$

Equation (20) completes the list of strain coefficient. which are needed to calculate $\partial L_{1} / \partial e_{y_{z}}$. Its numerical value (listed in Table VI) is $24 \%$ lower than the one determined from the experiments.
Figure 13 illustrates how the theoretical coefficien: $\partial L_{1} / \partial e_{y z}$ changes when changing the assumptions specified above. Figure 13(a) gives the dependence o: $\partial b_{d} / \partial e_{y z}$ assuming Eq. (20) to be valid. Figure $13(\mathrm{~b})$ shows the variation with $\partial\left(\ln H_{\varphi d}\right) / \partial e_{y z}$ using $\partial b_{d} / \partial c_{z}$, $=0.73$ as calculated from atomic $d$ functions. ${ }^{37}$
Two volume deformation potentials $\partial\left(E_{P}-L_{3^{u}}{ }^{u}\right) / \partial$ de (determined from the edge at 2.1 eV ) and $\partial\left(L_{1}-E_{F}\right) / \partial$ (from the edge at 4.3 eV ) are used to calculate the volume coefficients of $E_{d}$ and $E_{F}$ relative to $\Gamma_{1}$. Thi can be done more accurately than the large experiment: $:$ error of the $L_{1}-E_{F}$ deformation potential might sum gest. Recalling that the error is due to the uncertainty is the appropriate slope of $\epsilon_{2}$, we note that the relative deviation of the experimental value from the tric value is approximately equal for the volume and the shear strain deformation potentials.
Summing the two experimental volume deformatian potentials eliminates $E_{F}$; the sum $\partial\left(L_{1}-L_{3^{u}}\right) / \partial c$ cat be used to determine $\partial\left(\ln E_{d}\right) / \partial e$. In doing so, we always treat the normalization factor $\Omega^{-1 / 2}$ of $b_{d}$ an : $H_{\varphi d}$ explicitly and assume

$$
\partial\left(\ln H_{\varphi d}\right) / \partial k=\partial\left(\ln b_{d}\right) / \partial k
$$

which is the equivalent of Eq. (20). There are sevet. choices on how to proceed. One possibility is to use the coefficient $\partial\left(\ln b_{d}\right) / \partial k$ as calculated with atomic functions and a value for $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial e$ which is 2 smaller than the experimental one. Another cha would be to increase $\partial\left(\ln b_{d}\right) / \partial e_{y z}$ until the theoreti value of $\partial L_{1} / \partial e_{y z}$ matches the experimental one [ $[$; $13(\mathrm{a})]$, to increase $\partial\left(\ln b_{d}\right) / \partial k$ by the same factor, to use the experimental value of $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial c$. T. volume coefficient of $E_{d}$ turns out to be the same . both cases, proving that it does not depend drastica" on the strain coefficients of $b_{d}$ and $H_{\varphi d}$. Its numeri value is listed in Table VII. In Fig. 14, $\partial\left(L_{1}-L_{3^{4}}\right)$ is plotted as a function of the strain coefficients of $/$
its of the Fermi energy and of of the $d$ bands.

| it | Derived from <br> dHvA $^{\text {b }}$ | $\mathrm{DFJ}^{\circ}$ |
| :---: | :---: | :---: |
| 0.5 | -0.73 | -0.85 |
| 0.3 | -0.86 |  |
| $V / V$ is the relative change of the volus |  |  |

$$
=\partial\left(\ln b_{d}\right) / \partial c_{y z}
$$

the list of strain coefficien ulate $\partial L_{1} / \partial e_{y z}$. Its numeric ) is $24 \%$ lower than the o: -iments.
ow the theoretical coefficie: changing the assumptio: (a) gives the dependence 0) to be valid. Figure 13 (t $\partial\left(\ln H_{\psi d}\right) / \partial e_{y z}$ using $\partial b_{d} / \partial \varepsilon_{i}$ atomic $d$ functions. ${ }^{37}$
on potentials $\partial\left(E_{P}-L_{3}{ }^{u}\right) / /$
at 2.1 eV$)$ and $\partial\left(L_{1}-E_{F}\right) /($ ) are used to calculate th and $E_{F}$ relative to $\Gamma_{1}$. T $y$ than the large experimen: mation potential might sus or is due to the uncertainty:
2, we note that the relatis ental value from the tri ual for the volume and $t$. sotentials.
mental volume deformati the sum $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial e c$ $\left.\sim E_{d}\right) /$ de. In doing so, : tion factor $\Omega^{-1 / 2}$ of $b_{d}$ ar
$=\partial\left(\ln b_{d}\right) / \partial k$,
Eq. (20). There are sever One possibility is to use t? calculated with atomic $\left(L_{1}-L_{3}{ }^{u}\right) / \partial e$ which is $2 f^{f}$ cntal one. Another cho: ) $/ \partial e_{y_{2}}$ until the theoretic the experimental one [F: $0 k$ by the same factor, tue of $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial$ e. T tns out to be the same loes not depend drastical" $b_{d}$ and $H_{\varphi d}$. Its numeric In Fig. 14, $\partial\left(L_{1}-L_{3}{ }^{u}\right)$ he strain coefficients of
ad $H_{\rho d}$ in a fashion equivalent to that of Fig. 13. The sependence on $\partial\left(\ln E_{d}\right) / \partial e$ is also included [Fig. (14(b))]. In calculating the volume coefficient of $E_{F}$, we use sce experimental value of $\partial\left(E_{F}-L_{3}{ }^{u}\right) / \partial e$, the volume (eefficient of $E_{d}$ as calculated above, and Eq. (7), toecther with the strain coefficients of the tight binding wrameters (Table V). The resulting value of $\partial\left(\ln E_{F}\right) / \partial e$ s given in Table VII.
Assuming no strain dependence of $b_{d}$ and $H_{\varphi d}$ at all except for $\Omega^{-1 / 2}$ ), we find the theoretical values of $L_{1} / \partial e_{y z}$ and $\partial\left(L_{1}-L_{3}{ }^{u}\right) / \partial e$ to be 62 and $50 \%$ of the corresponding experimental numbers [Eqs. 13(a) and 14(a)], respectively. This part of the deformation potentials is mainly due to the strain dependence of $k^{2}$ ind, for hydrostatic deformation, to the strain depenLence of $\Omega^{-1 / 2}$.

## Discussion

The preceding analysis dealt with the observed structure in $W_{i j}$. A legitimate question is whether the energy bands predict more structure than actually abserved. Pure shear strain will produce a significant change in $\epsilon_{2}$ only for strongly or moderately localized transitions. Moreover, even if the transitions are bealized but have k vectors of low symmetry (i.e., seither parallel to [001] nor to [111]), there will be a signal for both trigonal and tetragonal strain (Table iiI) and the signal will tend to be small. Looking for iocalized $\Delta, X, \Lambda$, and $L$ singularities only, we expect the $X_{5} \rightarrow X_{4}{ }^{\prime}$ and the FS $\rightarrow L_{1}$ transitions to show up between 2 and 5.5 eV , as they do, i.e., the measurements are complete. On the other hand, hydrostatic strain will produce a signal for nonlocalized transitions :oo. Experimental examples are the maximum in $\|_{11}+2 W_{12}$ at 2.1 eV and the shoulder at 4.8 eV .
The energies of the identified transitions agree to within $\pm 0.1 \mathrm{eV}$ with the corresponding difference of the eigenvalues, calculated with Chodorow's ${ }^{26}$ potential. Band-structure calculations based on potentials difSerent from that of Chodorow deviate from experiment by as much as 1.5 eV . Table VIII compares the energies of the experimentally observed transitions with predictions of different calculations. ${ }^{13,14,42-44}$ There are ither experimental results which agree most closely with the result of the $E(\mathrm{k})$ calculation based on Chodorow's potential, the most important of which is the area of the neck, measured with the de Haas-van Mphen effect. The experimental numbers which were :e-examined recently ${ }^{45,46}$ agree with the calculation ${ }^{13,14,42}$ to within $11 \%$. For calculations with other

[^14]Table VIII. Energies of observed transitions in eV.

| Energy | Experiment | Chodorows |  |  |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| $E_{F}-L_{3^{4}}$ | $2.1 \pm 0.1$ | 2.1 | 2.3 | 1.6 | 3.2 |
| $X_{4^{\prime}}-X_{\mathrm{B}}$ | $4.0 \pm 0.1$ | 4.0 | 4.7 | 3.1 | 5.5 |
| $L_{1}-E_{F}$ | $4.15 \pm 0.1$ | 4.0 | 5.15 | 3.9 |  |

a References 13 and 14.
b References 13.

- References 42 and 43.
d Table II of Ref. 44.
potentials one might not get contact of the Fermi surface with the [111] face of the BZ at all. ${ }^{42}$
Thus, the experimental evidence for the superiority of the band structure calculated with Chodorow's potential is overwhelming. However, there is no theoretical formalism known today which tells us that we have to choose just this potential. For example, a self-consistent augmented-plane-wave calculation as the one reported by Snow and Waber ${ }^{44}$ will agree with the experimental results once the exchange term is properly adjusted, but there is no theoretical justification for such an adjustment.
Zallen ${ }^{47}$ measured the change of the reflectance with volume applying hydrostatic pressure directly to the crystal. His results are also listed in Table VI. He could quote only a lower limit for the deformation potential of the 2.1 -edge. Our method is much more sensitive here because the large slope of the edge produces a large $\Delta \epsilon_{2}$ even for the small deformation potential. The two experiments are of comparable accuracy in terms of energy shifts for the $4.3-\mathrm{eV}$ edge. The modulation experiment lost part of its advantage here because the slope is smaller and the slope of the background unknown. The results of the two measurements agree within the experimental error.
Objections might be raised against the procedure used here to calculate the deformation potentials. In particular, one ought to construct the tight-binding functions $d$ from resonance functions rather than from atomic orbitals, as discussed by Heine. ${ }^{39}$ However, this would have little effect on the $d$-sp overlap $b_{d}$, because the largest contribution to this integral comes from regions where the resonance function and the atomic $d$ function are identical (the maximum of the integrand lies at 0.53 of the nearest-neighbor distance). The calculated strain coefficients of the tight-binding integrals $\sigma, \pi, \delta$ (Table V) are higher than predicted by Heine's theory, which would give $R \partial(\ln \beta) / \partial R=-5$ ( $\beta=\sigma, \pi, \delta$ ), but their influence on the deformation potentials is small. Furthermore, it is not clear how the theory of Heine has to be modified if one abandons the muffin-tin approach, i.e., for overlapping potentials.
Two other calculations of the hydrostatic deformation potentials are known. ${ }^{43,48}$ Both are listed in

[^15]Table V. The agreement between the measured values and the ones calculated by Davis et al. ${ }^{43}$ would probably improve if Chodorow's potential were used instead of the one derived from the wave functions given by Watson. ${ }^{49}$ The strain coefficients of $E_{d}$ and $E_{F}$ given in Ref. 43 are listed in Table VII.

Using the de Haas-van Alphen effect, Templeton ${ }^{50}$ measured the change of the neck area with volume and found $\partial\left(\ln A_{n}\right) / \partial e=\frac{2}{3}(4.2 \pm 0.2)$. This information can be used to approximately calculate the strain coefficient of $E_{F}$. It is determined by Eqs. (7) and (18), neglecting the change of the effective mass of the $L_{2}{ }^{\prime}-Q$ - band. The numerical value of $\partial\left(\ln E_{F}\right) / \partial e$ listed in Table VII is about $34 \%$ lower than the one derived from the optical experiments. The agreement will be closer if the change of the effective mass is taken into account: Decreasing the volume $(e>0)$ decreases the $d-s p$ interaction; the $L_{2}{ }^{\prime}-Q$ - band will get closer to the freeelectron parabola (Fig. 9). Thus, including the change of the effective mass, the same change of the neck area requires a larger value of $\left|\partial\left(\ln E_{F}\right) / \partial e\right|$.

The $\Delta R / R$ signal measured with strained polycrystalline films ${ }^{3,11}$ shows some resemblance to the functional dependence of the hydrostatic effect $\left(Q_{11}+2 Q_{12}\right.$ in Fig. 7), probably with some admixture of the effect produced by trigonal shear strain $\left(Q_{44}\right)$. Indeed, one would expect the $\Delta R / R$ signal measured with strained polycrystalline films to be a linear combination of the functions $Q_{i j}$, provided the signal is due to the change of the reflectance of the material under study. The function $Q_{11}-Q_{12}$ is small for Cu and will therefore contribute but slightly to $\Delta R / R$ measured with polycrystalline films. However, the function $\Delta R / R$ given in Refs. 8 and 11 is not a simple linear combination of $Q_{11}+2 Q_{12}$ and $Q_{44}$. A positive function which increases with energy has to be added to reproduce $\Delta R / R$ as presented in Refs. 8 and 11. The maximum value of this function is of the same order of magnitude as the maximum value in $\Delta R / R$. We believe that this positive function is identical with an error signal produced, e.g., by the mechanical motion of the film. We also found such an error signal, if present, to be strongly energydependent. The functions $Q_{i j}$ presented here, which are characteristic of electropolished single crystals have zero values below 2 eV . The signal below 2 eV observed using polycrystalline films ${ }^{8,11}$ is probably due to the error signal only.

The FS $\rightarrow L_{1}$ transition was also identified in the photoemission measurements of Berglund and Spicer. ${ }^{19}$

[^16]The energy determined from this experiment is identica: with the one reported here. The authors introduced 1 l . concept of nondirect transitions in the analysis of thei: data, i.e., transitions which do not conserve k directly. The term "indirect transitions" was avoided becauc the authors wanted to include the possibility that processes different from the usual phonon-assisted trans: tions are important. The theoretical interpretation : these nondirect transitions is still under discussion (sce. e.g., Refs. 51 and 52). Berglund and Spicer conclude. from their data that the optical absorption in Cu i. dominated by nondirect transitions except for a vers small contribution (below $10 \%$ ) of the direct trans tions at $L$ mentioned above.

It is evident from the results presented here that direct transitions must be important. The structure it. $W_{11}-W_{12}$ which we identified with the $X_{5} \rightarrow I_{1}$ transition may serve as an example. One might try tu explain it as caused by nondirect transitions startin, from various initial states to the same final state $X_{\text {, }}$ The k degeneracy of $X_{4}{ }^{\prime}$ will be lifted by tetragonal shew: strain. This might cause the observed $W_{11}-W_{12}$. How ever, the selection rules for nondirect transitions wil generally differ from those for direct transitions. '1ts assumption $\left|M_{x}\right|^{2}=\left|M_{y}\right|^{2}=\left|M_{z}\right|^{2}$ might be adequat for such an averaging process. In this case, there wout be no first-order change of $\epsilon_{2}$ at all, i.e., $W_{11}-W_{12}$ woul? be zero, in contrast to the experimental result reporte here.

The sign ( $X$ transition) as well as the magnitu? ( $L$ transition) of the observed energy shift is consiste:" with the selection rules for direct transitions. Thus th nondirect transitions must have selection rules identi ... to those for direct transitions in order to be compatit. with our measurements.

The photoemission measurements ${ }^{19}$ on Cu can a' be explained if one assumes that the absorption abon 2 eV is dominated by direct interband transitions. ${ }^{53}$ I more natural to discuss the optical absorption in 4 . region in terms of direct transitions, because this $p$ cess is well established theoretically and accounts : all details of the experiments persented in this pap:

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[^17]
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